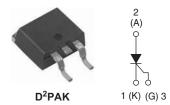


Vishay High Power Products

Surface Mountable

Phase Control SCR, 10 A



PRODUCT SUMMARY			
V _T at 6.5 A	< 1.15 V		
I _{TSM}	140 A		
V_{RRM}	800 V		

DESCRIPTION/FEATURES

The 10TTS08SPbF High Voltage Series of silicon controlled rectifiers are specifically designed for medium power switching and phase control applications. The glass passivation technology used has reliable operation up to 125 °C junction temperature.



RoHS

Typical applications are in input rectification (soft start) and these products are designed to be used with Vishay HPP input diodes, switches and output rectifiers which are available in identical package outlines.

This product has been designed and qualified for industrial level and lead (Pb)-free.

OUTPUT CURRENT IN TYPICAL APPLICATIONS					
APPLICATIONS	SINGLE-PHASE BRIDGE THREE-PHASE BRIDGE UNITS				
NEMA FR-4 or G-10 glass fabric-based epoxy with 4 oz. (140 μm) copper	2.5	3.5			
Aluminum IMS, R_{thCA} = 15 °C/W	6.3	9.5	A		
Aluminum IMS with heatsink, R _{thCA} = 5 °C/W	14.0	18.5			

[•] T_A = 55 °C, T_J = 125 °C, footprint 300 mm²

MAJOR RATINGS AND CHARACTERISTICS					
PARAMETER	TEST CONDITIONS	VALUES	UNITS		
I _{T(AV)}	Sinusoidal waveform	6.5	A		
I _{RMS}		10	A		
V _{RRM} /V _{DRM}		800	V		
I _{TSM}		140	Α		
V _T	6.5 A, T _J = 25 °C	1.15	V		
dV/dt		150	V/µs		
dl/dt		100	A/μs		
T _J	Range	- 40 to 125	°C		

VOLTAGE RATINGS			
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{DRM} , MAXIMUM PEAK DIRECT VOLTAGE V	I _{RRM} /I _{DRM} AT 125 °C mA
10TTS08SPbF	800	800	1.0

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ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS
Maximum average on-state current	I _{T(AV)}	T _C = 112 °C, 180° conduction half sine wave		6.5	
Maximum RMS on-state current	I _{T(RMS)}	1C = 112 C, 160 CONG	iction riali sirie wave	10	Α
Maximum peak, one-cycle,	1	10 ms sine pulse, rated	V _{RRM} applied, T _J = 125 °C	120	A
non-repetitive surge current	I _{TSM}	10 ms sine pulse, no volt	age reapplied, T _J = 125 °C	140	
Maximum 12t for fusing	l ² t	10 ms sine pulse, rated	V _{RRM} applied, T _J = 125 °C	72	A ² s
Maximum I ² t for fusing	1-1	10 ms sine pulse, no voltage reapplied, $T_J = 125$		100	A-5
Maximum I ² √t for fusing	I ² √t	$t = 0.1$ to 10 ms, no voltage reapplied, $T_J = 125$ °C		1000	A²√s
Maximum on-state voltage drop	V_{TM}	6.5 A, T _J = 25 °C		1.15	V
On-state slope resistance	r _t	T _J = 125 °C		17.3	mΩ
Threshold voltage	V _{T(TO)}			0.85	V
Maximum rayaraa and direct laakaga aurrant		T _J = 25 °C	V - Poted V /V	0.05	
Maximum reverse and direct leakage current	I_{RM}/I_{DM}	T _J = 125 °C	V _R = Rated V _{RRM} /V _{DRM}	1.0	mA
Typical holding current	I _H	Anode supply = 6 V, resistive load, initial $I_T = 1$ A		30	IIIA
Maximum latching current	lι	Anode supply = 6 V, resistive load		50	
Maximum rate of rise of off-state voltage	dV/dt	T _J = 25 °C		150	V/µs
Maximum rate of rise of turned-on current	dl/dt			100	A/µs

TRIGGERING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum peak gate power	P_{GM}		8.0	w
Maximum average gate power	$P_{G(AV)}$		2.0	VV
Maximum peak positive gate current	+I _{GM}		1.5	Α
Maximum peak negative gate voltage	-V _{GM}		10	V
Maximum required DC gate current to trigger	I _{GT}	Anode supply = 6 V, resistive load, T _J = - 65 °C	20	mA
		Anode supply = 6 V, resistive load, T _J = 25 °C	15	
		Anode supply = 6 V, resistive load, T _J = 125 °C	10	
		Anode supply = 6 V, resistive load, T _J = - 65 °C	1.2	
Maximum required DC gate voltage to trigger	V _{GT}	Anode supply = 6 V, resistive load, T _J = 25 °C	1	V
		Anode supply = 6 V, resistive load, T _J = 125 °C	0.7	V
Maximum DC gate voltage not to trigger	V_{GD}	T _J = 125 °C, V _{DRM} = Rated value 0.2 0.1		
Maximum DC gate current not to trigger	I_{GD}			mA

SWITCHING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Typical turn-on time	t _{gt}	T _J = 25 °C	0.8	
Typical reverse recovery time	t _{rr}	T 105 °C	3	μs
Typical turn-off time	tq	T _J = 125 °C	100	



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PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range	T _J , T _{Stg}		- 40 to 125	°C
Soldering temperature	T _S	For 10 s (1.6 mm from case)	240	
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	1.5	°C/W
Typical thermal resistance, junction to ambient (PCB mount)	R _{thJA} ⁽¹⁾		40	C/VV
Approximate weight			2	g
Approximate weight			0.07	oz.
Marking device		Case style D ² PAK (SMD-220)	10TTS	08S

Note

 $^{^{(1)}}$ When mounted on 1" square (650 mm²) PCB of FR-4 or G-10 material 4 oz. (140 μm) copper 40 °C/W For recommended footprint and soldering techniques refer to application note #AN-994

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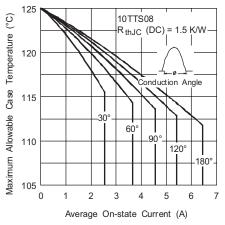


Fig. 1 - Current Rating Characteristics

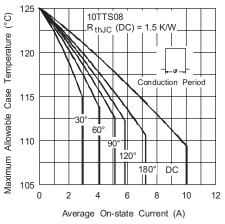


Fig. 2 - Current Rating Characteristics

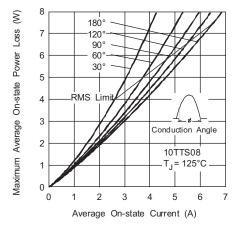


Fig. 3 - On-State Power Loss Characteristics

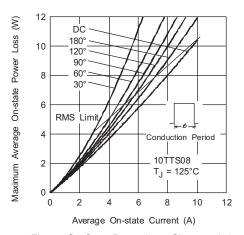


Fig. 4 - On-State Power Loss Characteristics

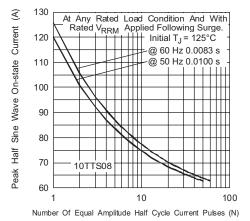


Fig. 5 - Maximum Non-Repetitive Surge Current

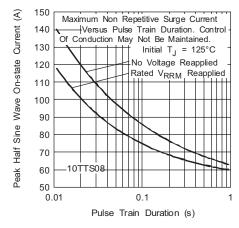


Fig. 6 - Maximum Non-Repetitive Surge Current



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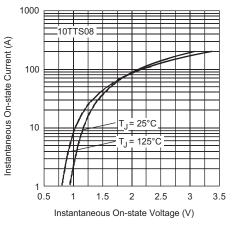


Fig. 7 - On-State Voltage Drop Characteristics

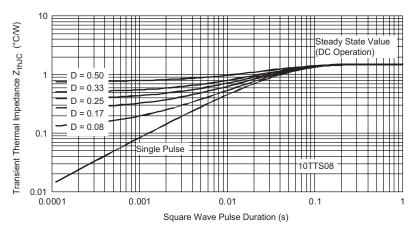


Fig. 8 - Thermal Impedance Z_{thJC} Characteristics

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ORDERING INFORMATION TABLE

1 - Current rating, RMS value

2 - Circuit configuration:

T = Single thyristor

3 - Package:

T = TO-220AC

4 - Type of silicon:

S = Converter grade

5 - Voltage code x 100 = V_{RRM}

- S = TO-220 D²PAK (SMD-220) version

7 - Tape and reel option:

• TRL = Left reel

• TRR = Right orientation reel

8 - • None = Standard production

• PbF = Lead (Pb)-free

LINKS TO RELATED DOCUMENTS			
Dimensions http://www.vishay.com/doc?95046			
Part marking information	http://www.vishay.com/doc?95054		
Packaging information	http://www.vishay.com/doc?95032		



Vishay

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